

# P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
- 30	0.020 at V <sub>GS</sub> = - 10 V	- 9.1		
	0.035 at V <sub>GS</sub> = - 4.5 V	- 6.9		

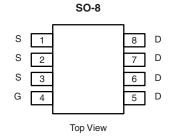
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET<sup>®</sup> Power MOSFET
- Advanced High Cell Density Process
- Compliant to RoHS Directive 2002/95/EC

# Pb-free RoHS COMPLIANT HALOGEN FREE Available

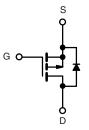
#### **APPLICATIONS**

- Load Switches
- Battery Switch



Ordering Information: Si4435BDY-T1-E3 (Lead (Pb)-free)

Si4435BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unles	ss otherwise r	noted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 30		٧	
Gate-Source Voltage		V <sub>GS</sub>	± 20			
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 9.1	- 7	^	
	T <sub>A</sub> = 70 °C		- 7.3	- 5.6		
Pulsed Drain Current		I <sub>DM</sub>	- 50		Α	
Continuous Diode Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 2.1	- 1.25		
	T <sub>A</sub> = 25 °C	В	2.5	1.5	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	$P_{D}$	1.6	0.9	VV	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manian una lumation ta Austrianti	t ≤ 10 s	R <sub>thJA</sub>	40	50	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		70	85	
Maximum Junction-to-Foot (Drain)	Steady State	$R_{thJF}$	18	22	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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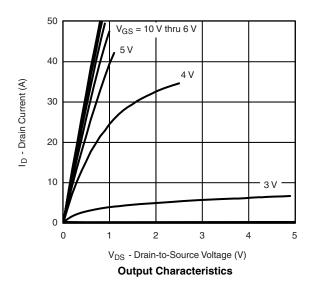
<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3	V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zava Cata Valtaga Dvain Current	1	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V			- 1	μА		
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			- 5			
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = - 5 V, V <sub>GS</sub> = - 10 V	- 40			Α		
	D	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 9.1 A		0.015	0.020	Ω		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 6.9 A		0.025	0.035			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 9.1 A		24		S		
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 2.1 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V		
Dynamic <sup>b</sup>								
Total Gate Charge	$Q_g$			33	70			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -9.1 \text{ A}$		5.8		nC		
Gate-Drain Charge	Q <sub>gd</sub>			8.6		1		
Turn-On Delay Time	t <sub>d(on)</sub>			10	15			
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 15 V, $R_L$ = 15 $\Omega$		15	25			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ - 1 A, $V_{GEN}$ = - 10 V, $R_g$ = 6 $\Omega$		110	170	ns		
Fall Time	t <sub>f</sub>			70	110			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 2.1 A, dI/dt = 100 A/μs		60	90			

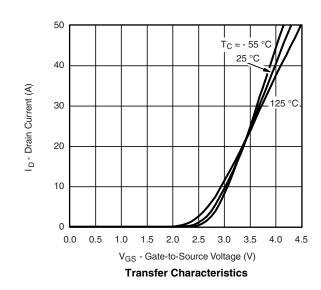
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

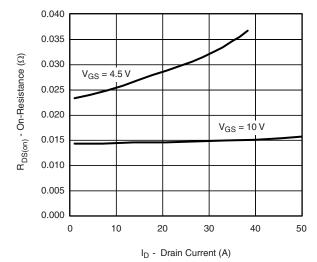




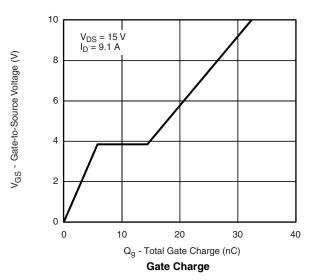


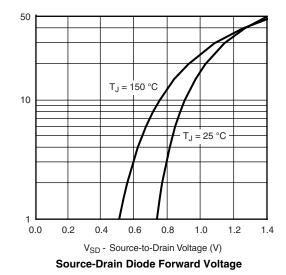


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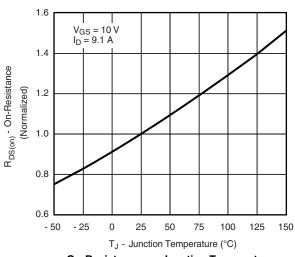
**On-Resistance vs. Drain Current** 



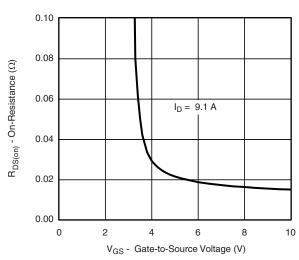


2400 C<sub>iss</sub> C<sub>oss</sub> C<sub>oss</sub> 0 5 10 15 20 25 30

V<sub>DS</sub> - Drain-to-Source Voltage (V) **Capacitance** 



On-Resistance vs. Junction Temperature



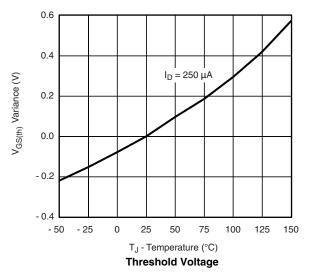
On-Resistance vs. Gate-to-Source Voltage

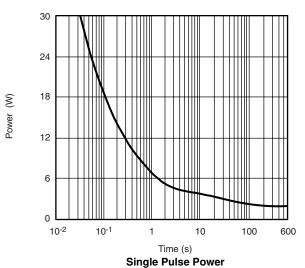
Is - Source Current (A)

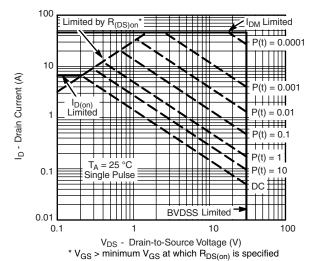
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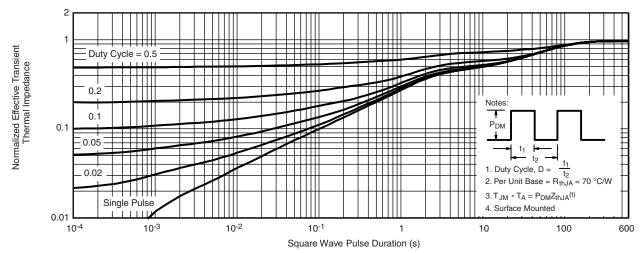
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







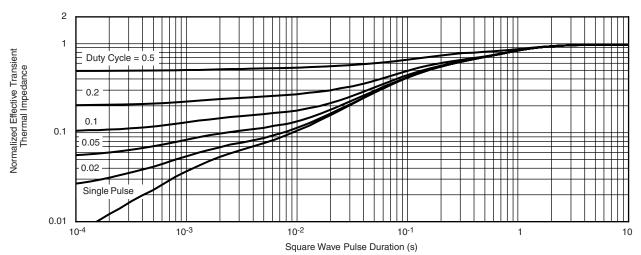
Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



# TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

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